Diode Semiconductor Device - Page 1 of 1



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Inclosure I	
Glass	
Overall Le	-
	195 inches and 0.350 inches
Terminal L	-
1.000 inche	
Overall Dia	
	215 inches and 0.265 inches
	Internally-electrically Connected To Case:
Cathode	
Mounting I	Method:
Terminal	
Features P	
	y sealed case
	uctor Material:
Silicon	
-	ting In Volts Per Characteristic:
-	ator voltage
	lerance In Percent:
-5.0/+5.0	
	ting Per Characteristic:
	nperes all primaries horsepower metric
	ing Per Characteristic:
	mall-signal input power, common-collector preset
Maximum	Operating Tempurature Per Measurement Point:
-	ees celsius ambient air
Test Data	Document:
81349-mil-p	orf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
	cludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmer	ntal and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal T	ype And Quantity:
2 uninsulate	ed wire lead
Shelf Life:	
N/a	
Unit Of Me	asure:
Demilitariz	ation:
No	
Fiig:	
A110a0	
Mil-std (mi	litary Standard):
Mil-prf-1950	00 spec.